
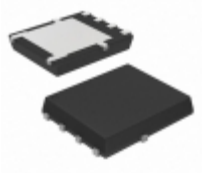
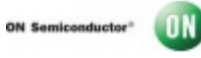
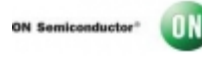
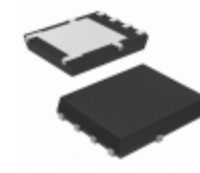
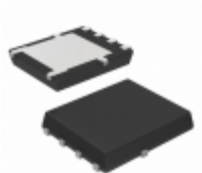
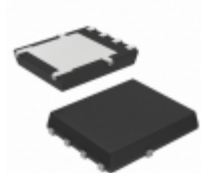
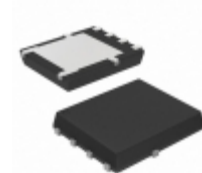
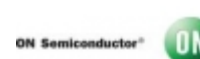
	<h2 style="color: red;">NTMFS4C10NT1G</h2>
	<p>Hersteller-Teilenummer: NTMFS4C10NT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 8.2A SO8FL</p> <p>Datenblätter:  NTMFS4C10NT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 130067 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMFS4C10NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 8.2A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	130067 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	750mW (Ta), 23.6W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.2A (Ta)
Rds On (Max) @ Id, Vgs	6.95 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9.7nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	987pF @ 15V
Verpackung	Tape & Reel (TR)

NTMFS4C10NT1G ist neu im Original, Suche NTMFS4C10NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4C10NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4C10NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMFS4C250NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 11A SO8FL</p>	 <p>NTMFS4C10NAT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 16.4A 46A 5DFN</p>	 <p>NTMFS4C10NBT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 16.4A 46A 5DFN</p>	 <p>NTMFS4C10NT1G-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.2A SO8FL</p>
 <p>NTMFS4C13NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 38A SO8FL</p>	 <p>NTMFS4C09NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 52A SO8FL</p>	 <p>NTMFS4C13NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 38A SO8FL</p>	 <p>NTMFS4C10NAT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.2A SO8FL</p>

heiße Teile

Mehr

NTMFS4935N	NTMFS4935NT1G	NTMFS4936N	NTMFS4936NT1G	NTMFS4937N
NTMFS4937NT1G	NTMFS4939NT1G	NTMFS4939NT3G	NTMFS4941NT1G	NTMFS4943NT1G
NTMFS4945NT1G	NTMFS4946N	NTMFS4946NT1G	NTMFS4955NT1G	NTMFS4982NFT1G
NTMFS4983NBFTG	NTMFS4983NFT1G	NTMFS4985NFT1G	NTMFS4C05N	NTMFS4C05NT1G
NTMFS4C06N	NTMFS4C06NT1G	NTMFS4C08NT1G	NTMFS4C09NAT1G	NTMFS4C09NT1G
NTMFS4C13NT1G	NTMFS4C35N	NTMFS4C55NT1G	NTMFS4C58NT1G	NTMFS4C800NT1G
NTMFS5844NLT1G	NTMFS5C404NLT1G	NTMFS5C612NLT1G	NTMFS5C628NLT1G	NTMFS5C646NLT1G
NTMFS5C670NLT1G	NTMS10P02	NTMS10P02R2	NTMS10P02R2G	NTMS3P03R2
NTMS3P03R2G	NTMS4101PR2G	NTMS4105NR2G	NTMS4107NR2G	NTMS4176PR2G
NTMS4177P	NTMS4177PR2G	NTMS4404NR2G	NTMS4503NR2G	NTMS4700NR

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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